

Prospective Data

Insulated Gate Bi-Polar Transistor Type T0850VB25E

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{CES}	Collector – emitter voltage	2500	V
$V_{DC\ link}$	Permanent DC voltage for 100 FIT failure rate.	1250	V
V_{GES}	Peak gate – emitter voltage	± 20	V

	RATINGS	MAXIMUM LIMITS	UNITS
$I_{C(DC)}$	Continuous DC collector current, IGBT	850	A
I_{CRM}	Repetitive peak collector current, $t_p=1ms$, IGBT	1700	A
I_{ECO}	Maximum reverse emitter current, $t_p=100\mu s$, (note 2 & 3)	850	A
P_{MAX}	Maximum power dissipation, IGBT (Note 2)	4.4	kW
T_{jop}	Operating temperature range.	-40 to +125	$^{\circ}C$
T_{stg}	Storage temperature range.	-40 to +125	$^{\circ}C$

Notes: -

- 1) Unless otherwise indicated $T_j = 125^{\circ}C$.
- 2) $T_{sink} = 25^{\circ}C$, double side cooled.
- 3) The use of an anti-parallel diode is recommended.

Characteristics

IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
$V_{CE(sat)}$	Collector – emitter saturation voltage	-	2.05	2.35	$I_C = 850A, V_{GE} = 15V, T_j = 25^\circ C$	V
		-	2.90	3.20	$I_C = 850A, V_{GE} = 15V$	V
V_{T0}	Threshold voltage	-	-	1.29	Current range: 280 – 850A	V
r_T	Slope resistance	-	-	2.25		m Ω
$V_{GE(TH)}$	Gate threshold voltage	-	5.8	6.3	$V_{CE} = V_{GE}, I_C = 75mA$	V
I_{CES}	Collector – emitter cut-off current	-	8	25	$V_{CE} = V_{CES}, V_{GE} = 0V$	mA
I_{GES}	Gate leakage current	-	4	± 15	$V_{GE} = \pm 20V$	μA
C_{ies}	Input capacitance	-	110	-	$V_{CE} = 25V, V_{GE} = 0V, f = 1MHz$	nF
$t_{d(on)}$	Turn-on delay time	-	1.1	-	$I_C = 850A, V_{CE} = 1250V, di/dt = 1500A/\mu s$	μs
$t_r(V)$	Rise time	-	2	-		μs
$Q_{g(on)}$	Turn-on gate charge	-	6.5	-	$V_{GE} = \pm 15V, L_s = 200nH$	μC
E_{on}	Turn-on energy	-	2	-	$R_{g(ON)} = 3.0\Omega, R_{g(OFF)} = 6.8\Omega, C_{GE} = 100nF$	J
$t_{d(off)}$	Turn-off delay time	-	1.5	-	Freewheel diode type E0800QC25C	μs
$t_f(I)$	Fall time	-	6	-	(Note 3)	μs
$Q_{g(off)}$	Turn-off gate charge	-	6	-		μC
E_{off}	Turn-off energy	-	1.4	-		J
I_{SC}	Short circuit current	-	2400	-	$V_{GE} = +15V, V_{CC} = 1250V, V_{CEmax} \leq V_{CES}, t_p \leq 10\mu s$	A

Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
R_{thJK}	Thermal resistance junction to sink, IGBT	-	-	22.5	Double side cooled	K/kW
		-	-	35.3	Collector side cooled	K/kW
		-	-	65.3	Emitter side cooled	K/kW
F	Mounting force	11	-	16	Note 2	kN
W_t	Weight	-	0.65	-		kg

Notes:-

- 1) Unless otherwise indicated $T_j = 125^\circ C$.
- 2) Consult application note 2008AN01 for detailed mounting requirements
- 3) C_{GE} is additional gate – emitter capacitance added to output of gate drive

Curves

Figure 1 – Typical collector-emitter saturation voltage characteristics

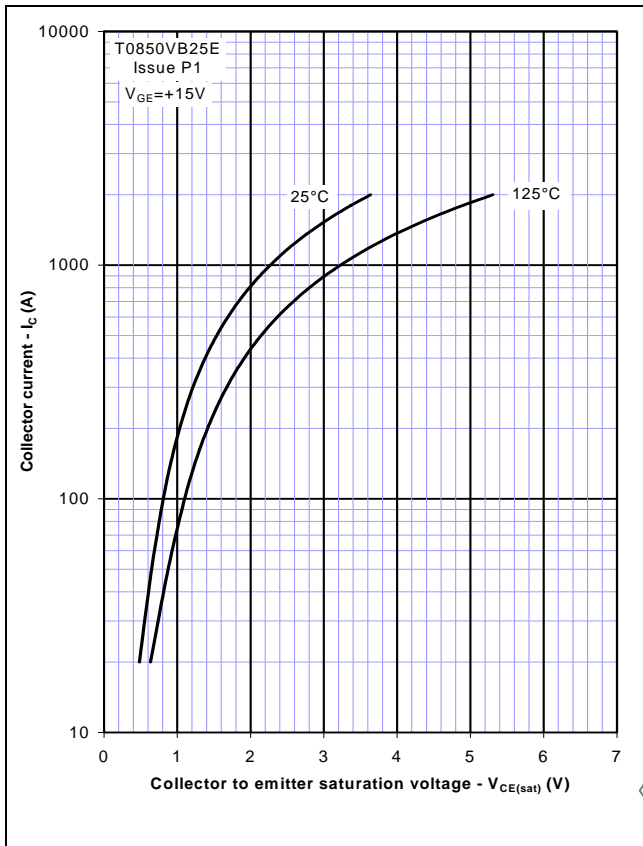


Figure 2 – Typical output characteristic

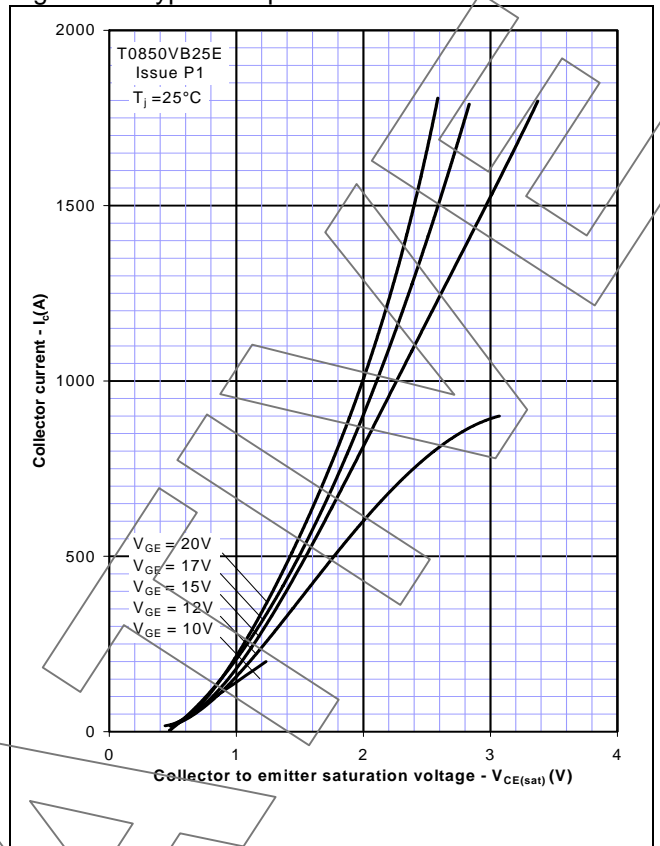


Figure 3 – Typical output characteristic

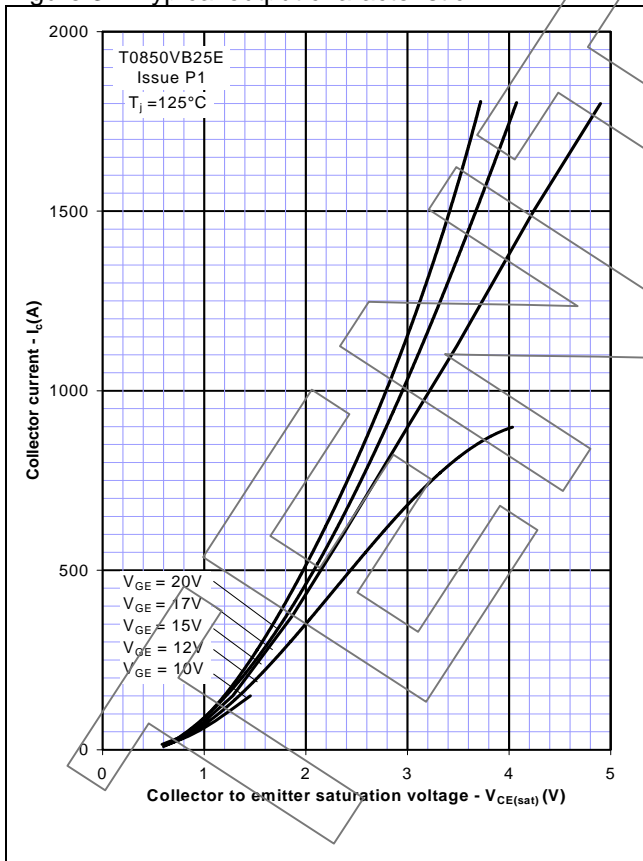


Figure 4 – Typical turn-on delay time vs gate resistance

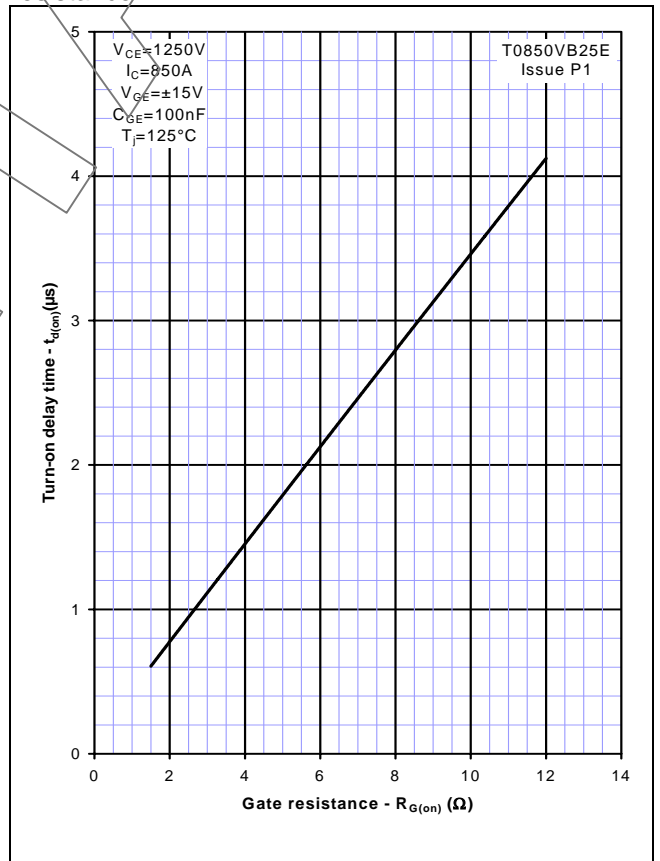


Figure 5 – Typical turn-off delay time vs. gate resistance

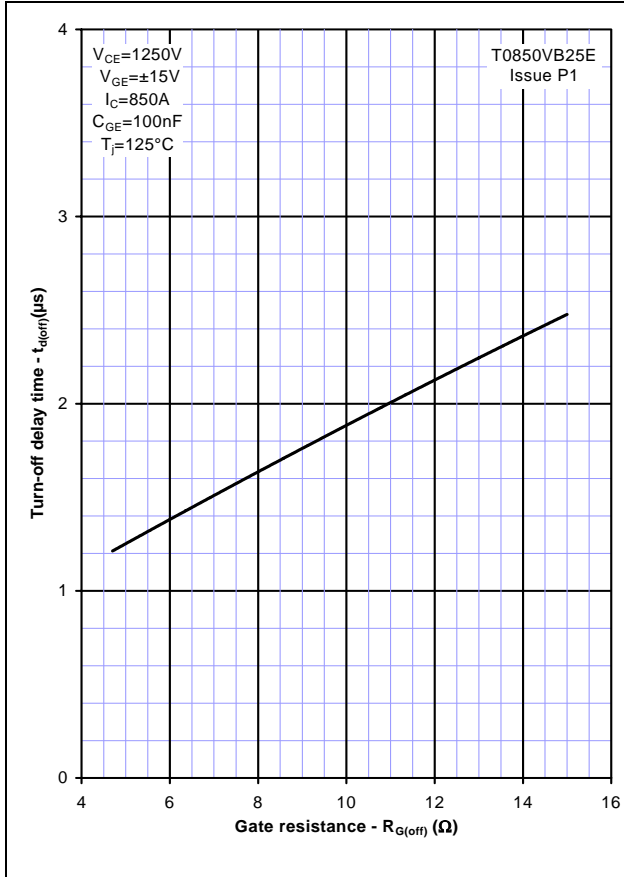


Figure 6 – Typical turn-on energy vs. collector current

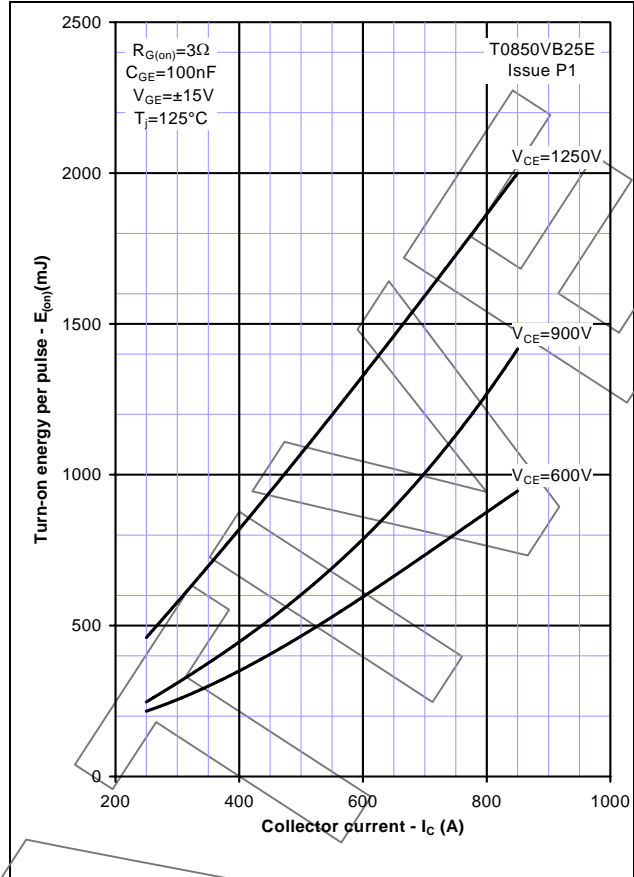


Figure 7 – Typical turn-on energy vs. di/dt

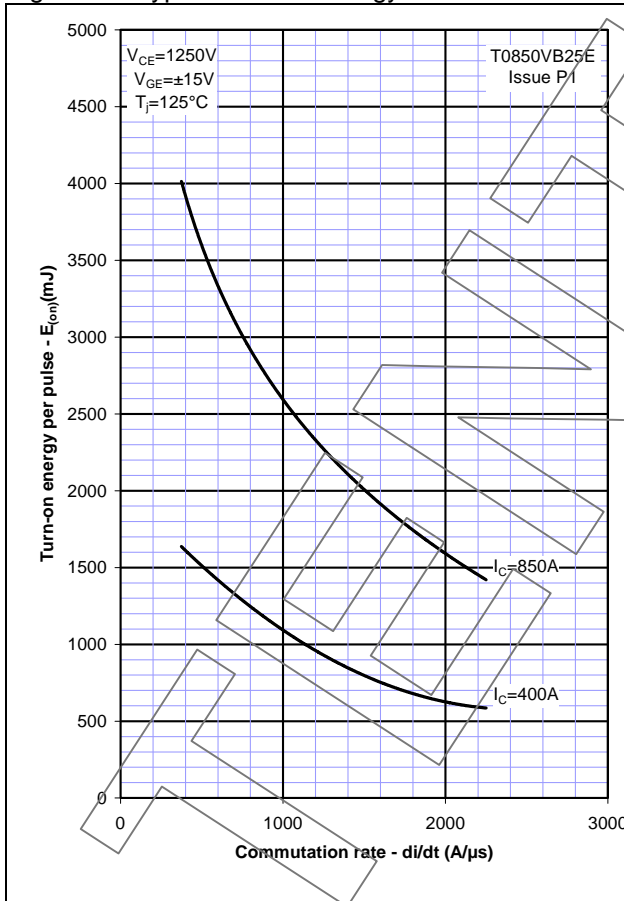


Figure 8 – Typical turn-off energy vs. collector current

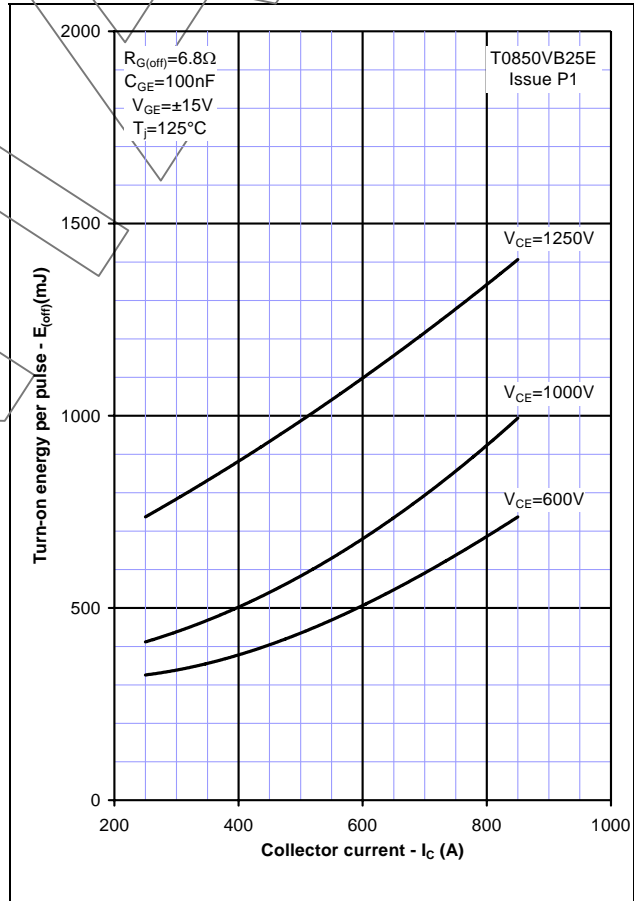


Figure 9 – Turn-off energy vs voltage

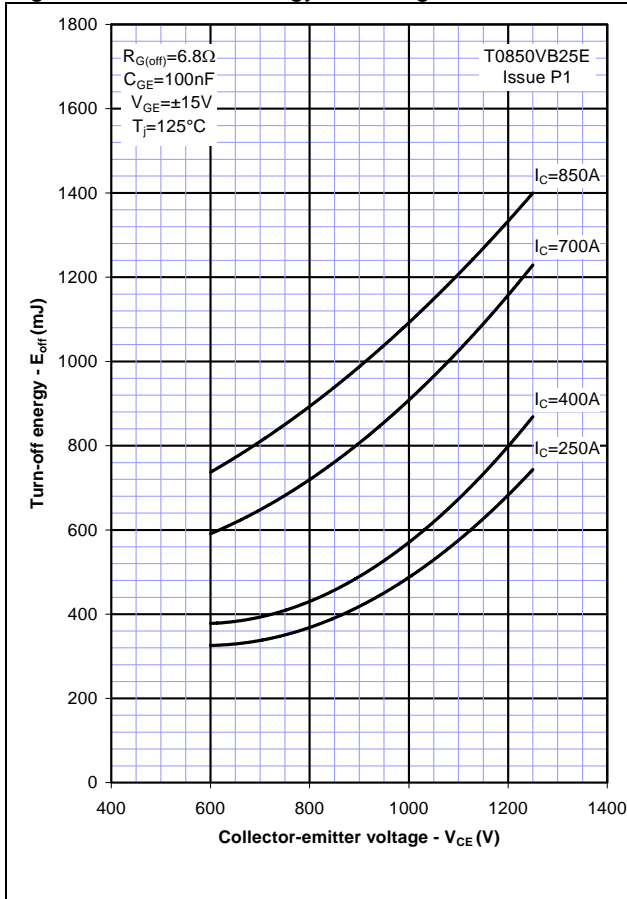


Figure 10 – Safe operating area

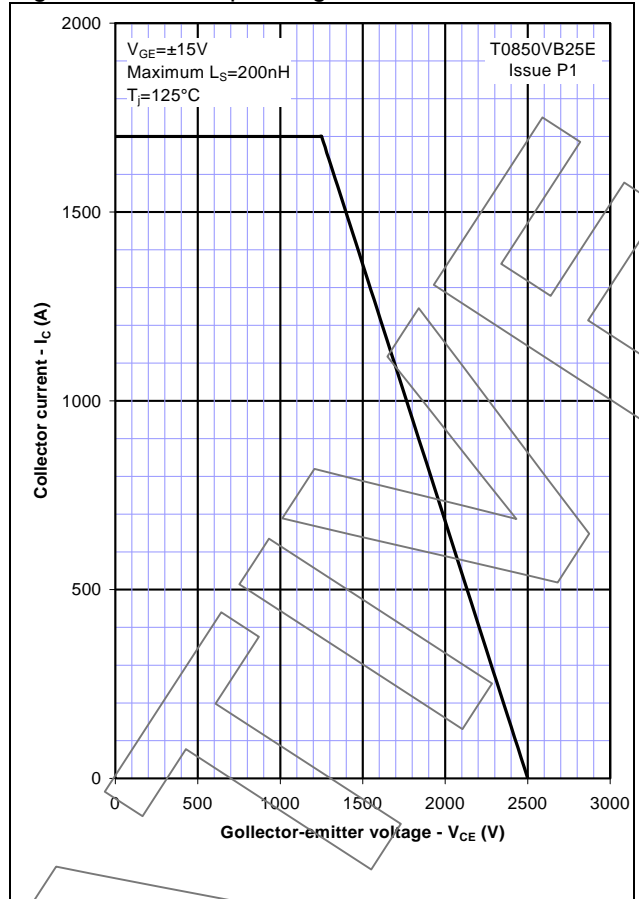
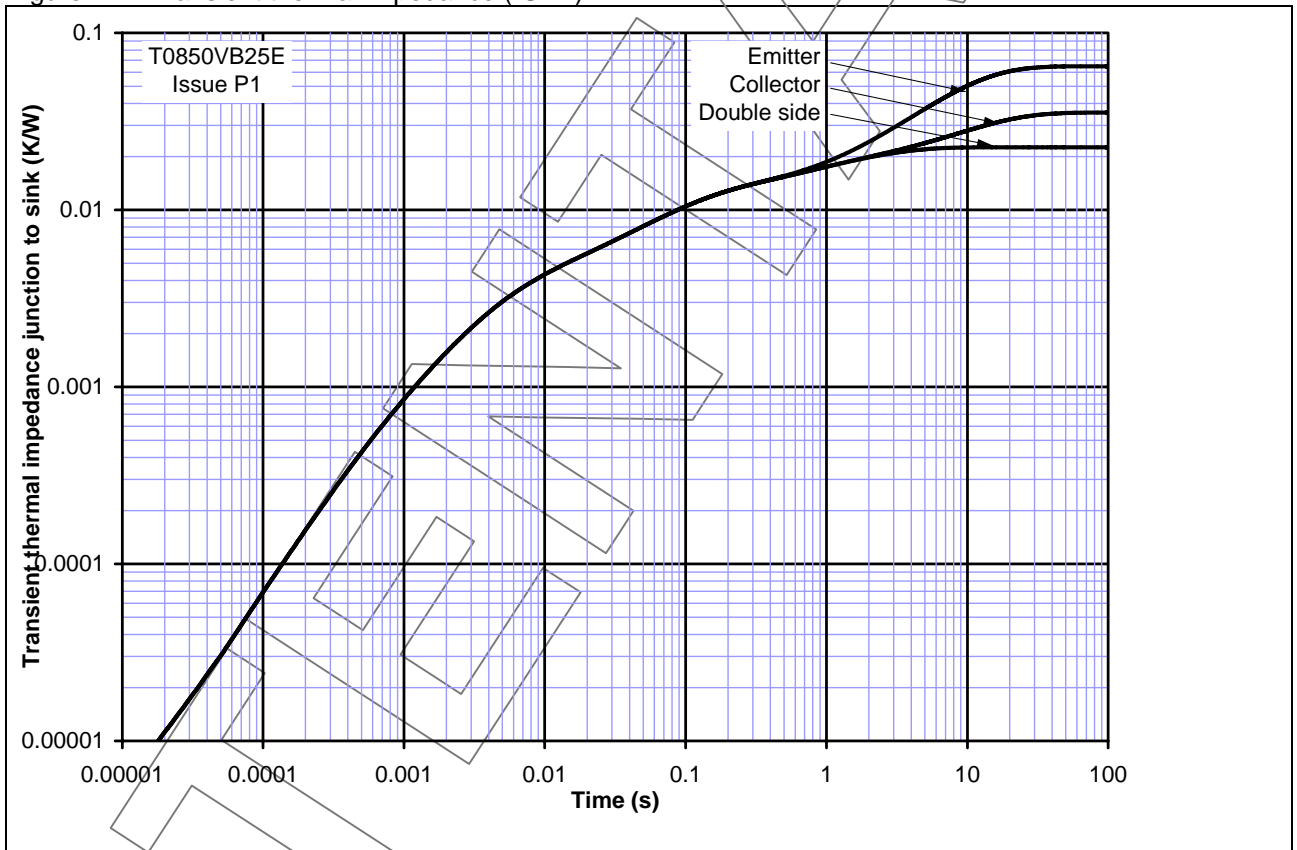
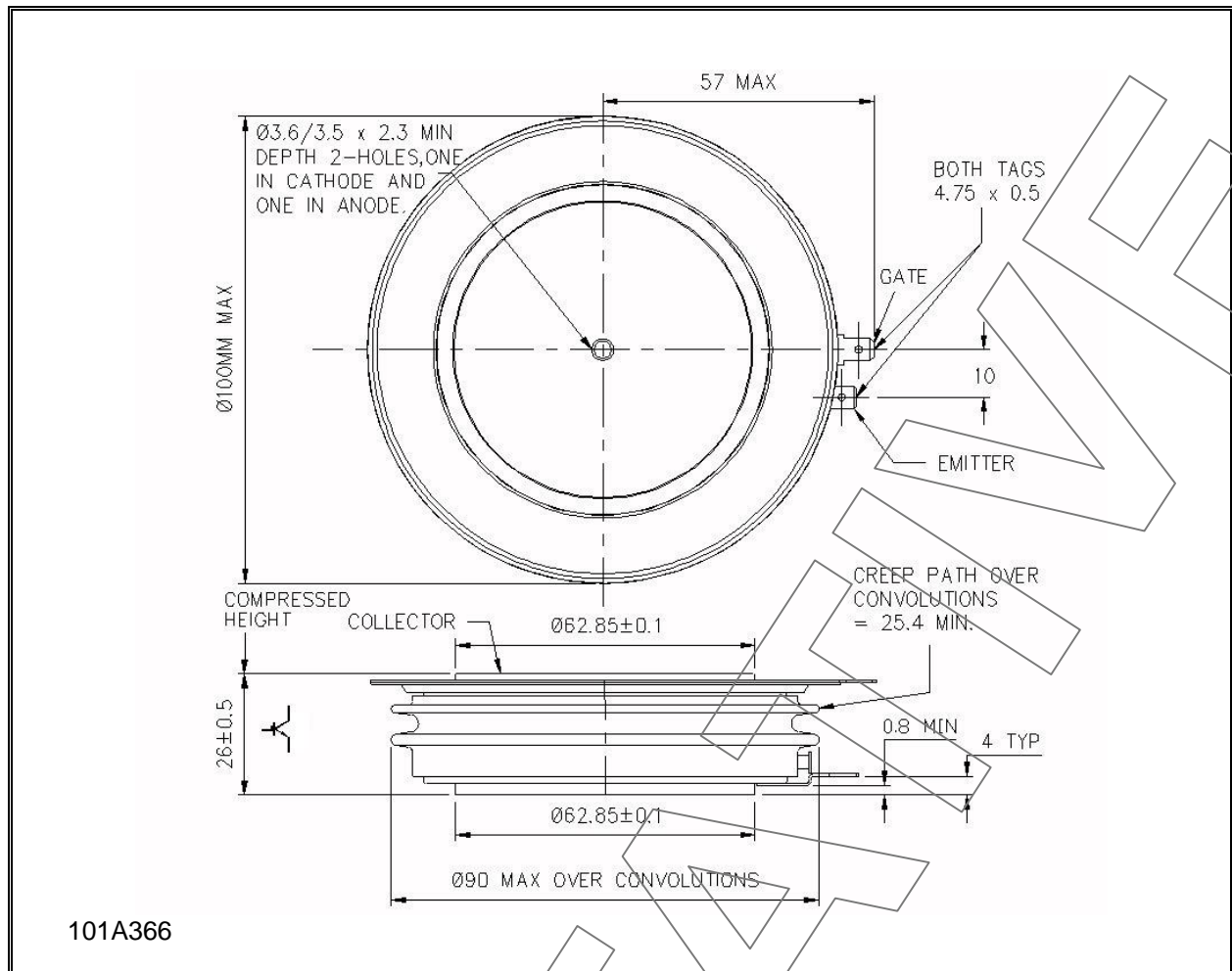


Figure 11 – Transient thermal impedance (IGBT)



Outline Drawing & Ordering Information



ORDERING INFORMATION			
		(Please quote 10 digit code as below)	
T0850	VB	25	E
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 25	Fixed format code

Typical order code: T0850VB25E ($V_{CES} = 2500V$)

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